NPN Epitaxial Planar Silicon Transistor



2SC4402

VHF/UHF Mixer, Local Oscillator, Low-Voltage Amplifier Applications

Applications

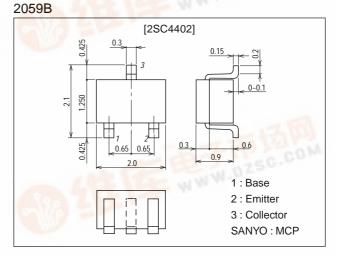
· VHF/UHF MIX/OSC, low-voltage high-frequency amplifiers.

Features

- · Low-voltage operation
 - : $f_T=3.0GHz$ typ ($V_{CE}=3V$)
 - : MAG=12dB typ (V_{CE} =3V, I_{C} =10mA)
 - : NF=1.5dB typ (V_{CE} =3V, I_{C} =5mA)
- · Very small-sized package permitting 2SC4402applied sets to be made smaller and slimmer.

Package Dimensions

unit:mm



Specifications

Absolute Maximum Ratings at Ta = 25°C

Doromotor	Cymphal	Conditions	Dotings	Unit
Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	VCBO		25	V
Collector-to-Emitter Voltage	V _{CEO}		15	V
Emitter-to-Base Voltage	V _{EBO}	pall .	3	V
Collector Current	IC	THE TAX	50	mA
Collector Dissipation	PC	and the same of th	150	mW
Junction Temperature	Tj	A SET THE W	150	°C
Storage Temperature	Tstg	- (S) (A) - C	-55 to +150	°C

Electrical Characteristics at Ta = 25°C

Parameter	Symbol	Conditions	Ratings			Unit
Falametel			min	typ	max	Onit
Collector Cutoff Current	I _{CBO}	V _{CB} =15V, I _E =0			1.0	μΑ
Emitter Cutoff Current	I _{EBO}	V _{EB} =1V, I _C =0			1.0	μA
DC Current Gain	hFE	V _{CE} =3V, I _C =10mA	40*		200*	
Gain-Bandwidth Product	fT	V _{CE} =3V, I _C =10mA		3.0	1773	GHz
Output Capacitance	C _{ob}	V _{CB} =3V, f=1MHz	40.0	0.85	1.5	pF
Reverse Transfer Capacitance	C _{re}	V _{CB} =3V, f=1MHz	-	0.8	30.	pF

 \ast : The 2SC4402 is classified by 10mA h_{FE} as follows :

40 2 80 60 3 120 100 4 200

(Note) Marking: PT h_{FE} rank: 2, 3, 4

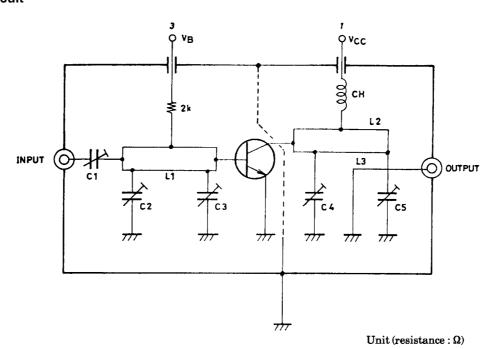
- For CP package version, use the 2SC4365.
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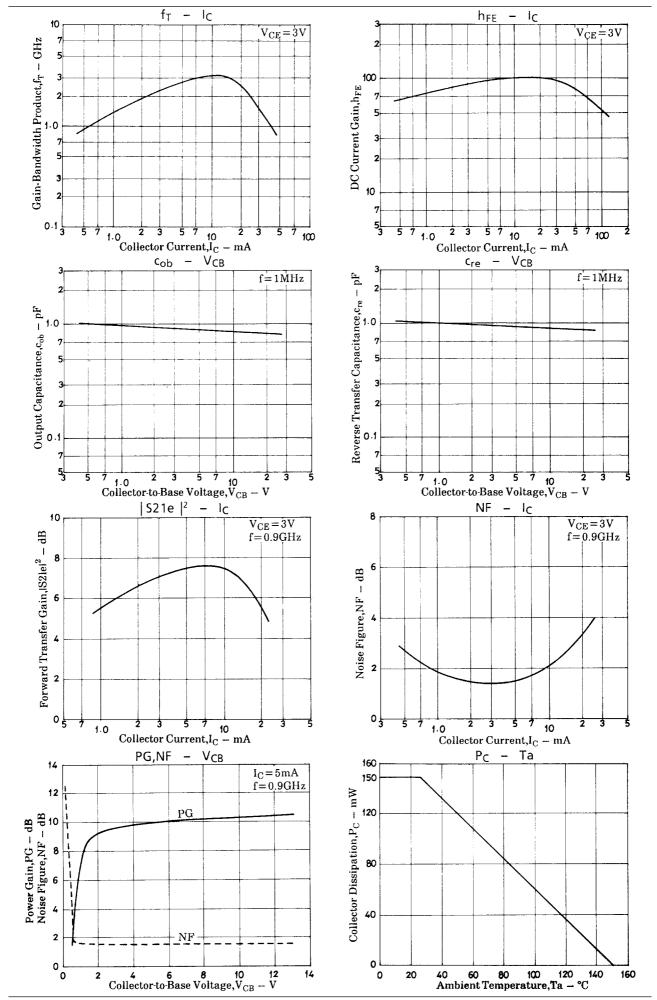
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Parameter	Symbol	Conditions	Ratings			Unit
Faiailletei	Symbol	Conditions	min	typ	max	Offic
Forward Transfer Gain	S21e ²	V _{CE} =3V, I _C =10mA, f=0.9GHz		7		dB
Maximum Available Power Gain	MAG	V _{CE} =3V, I _C =10mA, f=0.9GHz		12		dB
Noise Figure	NF	V _{CE} =3V, I _C =5mA, f=0.9GHz See specified Test Circuit.		1.5	3.0	dB

NF Test Circuit



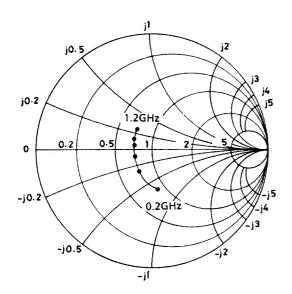
	900MHz		
C1	~5pF		
C2	~10pF		
C3	~10pF		
C4	~10pF		
C5	~10pF		
L1	W ≈ 1.5mm, I ≈ 25mm		
	Strip line		
L2	W ≈ 4mm, I ≈ 25mm		
	Strip line		
L3	0.5φ, I ≈ 40mm		
CH	2t+bead core		

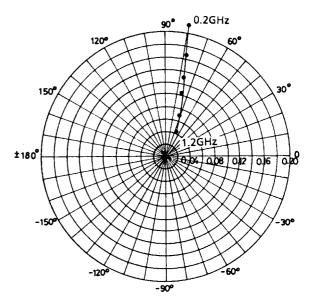


S11e: $V_{CE} = 3V$ $I_C = 5mA$

f = 0.2GHz step

S12e: $V_{CE} = 3V$ $I_C = 5mA$ f = 0.2GHz step

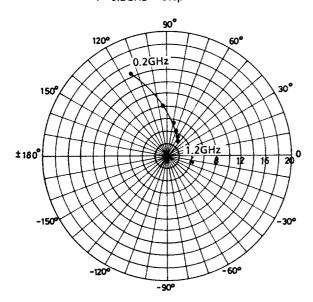


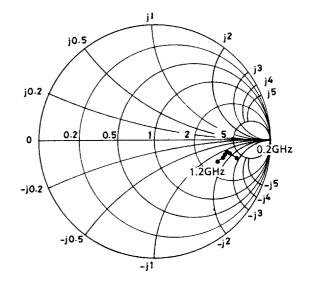


S21e: $V_{CE} = 3V$ $I_C = 5mA$

f = 0.2GHz step

S22e: $V_{CE} = 3V$ $I_C = 5mA$ f = 0.2GHzstep





2SC4402

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